

DC Input 4-Pin Phototransistor Optocoupler

Features

- High isolation 5000 VRMS
- CTR flexibility available see order information
- DC input with transistor output
- External Creepage ≥ 7.5mm (S/SL Type)
- External Creepage ≥ 8.0mm (SLM Type)
- Operating temperature range 55 °C to 110 °C
- Regulatory Approvals
 - UL UL1577 (E364000)
 - VDE EN60747-5-5(VDE0884-5)
 - CQC GB4943.1, GB8898
 - IEC60065, IEC60950

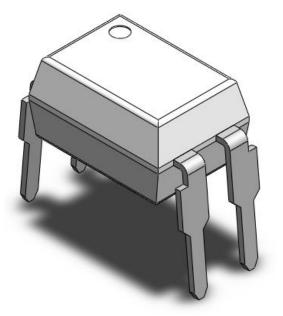
Description

The CT817 series consists of a photo transistor optically coupled to a gallium arsenide Infrared-emitting diode in a 4-lead DIP package different lead forming options.

Applications

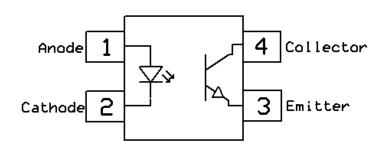
- Switch mode power supplies
- Computer peripheral interface
- Microprocessor system interface

Package Outline



Note: Different lead forming options available. See package dimension.

Schematic





DC Input 4-Pin Phototransistor Optocoupler

Absolute Maximum Rating at 25°C

| Symbol | Parameters | Ratings | Units | Notes |
|-----------------------|--|------------|------------------|-------|
| Viso | Isolation voltage (AC, 1 minute) | 5000 | V _{RMS} | |
| Ртот | Total power dissipation | 200 | mW | |
| Topr | Operating temperature | -55 ~ +110 | °C | |
| Тѕтс | Storage temperature | -55 ~ +150 | °C | |
| TsoL | Soldering temperature | 260 | °C | |
| Emitter | | | | |
| I _F | Forward current | 60 | mA | |
| I _{F(TRANS)} | Peak transient current (≤1µs P.W,300pps) | 1 | Α | |
| VR | Reverse voltage | 6 | V | |
| PD | Emitter power dissipation | 100 | mW | |
| Detector | , | | | |
| PD | Detector power dissipation | 150 | mW | |
| B _{VCEO} | Collector-Emitter Breakdown Voltage | 35 | V | |
| B _{VECO} | Emitter-Collector Breakdown Voltage | 6 | V | |
| Ic | Collector Current | 50 | mA | |



DC Input 4-Pin Phototransistor Optocoupler

Electrical Characteristics $T_A = 25$ °C (unless otherwise specified)

Emitter Characteristics

| Symbol | Parameters | Test Conditions | Min | Тур | Max | Units | Notes |
|--------------------------------|-------------------|----------------------|-----|------|-----|-------|-------|
| V _F Forward voltage | | I _F =10mA | - | 1.24 | 1.4 | V | |
| I _R | Reverse Current | $V_R = 6V$ | - | - | 5 | μΑ | |
| Cin | Input Capacitance | f= 1MHz | - | 10 | 30 | pF | |

Detector Characteristics

| Symbol | Parameters | Test Conditions | Min | Тур | Max | Units | Notes |
|-------------------|--------------------------------|--|-----|-----|-----|-------|-------|
| B _{VCEO} | Collector-Emitter Breakdown | Ic= 100μA | 35 | - | - | V | |
| B _{VECO} | Emitter-Collector Breakdown | I _E = 100μA | 6 | - | - | V | |
| ICEO | Collector-Emitter Dark Current | V _{CE} = 20V, I _F =0mA | - | - | 100 | nA | |

Transfer Characteristics

| Symbol | Parameters | | Test Conditions | Min | Тур | Max | Units | Notes |
|---------------|------------------------------|--------|---|--------------------|------|-----|-------|-------|
| | Current Transfer Ratio CT817 | CT817 | I _F = 5mA, V _{CE} = 5V | 50 | - | 600 | % | |
| | | CT817A | | 80 | - | 160 | | |
| CTR | | CT817B | | 130 | - | 260 | | |
| | | CT817C | | 200 | - | 400 | | |
| | | CT817D | | 300 | - | 600 | | |
| V | Collector-Emitter Saturation | | I _F = 20mA, I _C = 1mA | | 0.1 | 0.2 | V | |
| $V_{CE(SAT)}$ | Voltage | | IF- ZUIIA, IC- IIIIA | - | 0.1 | 0.2 | V | |
| Rio | Isolation Resistance | | V _{IO} = 500V _{DC} | 5x10 ¹⁰ | - | - | Ω | |
| Cıo | Isolation Capacitance | | f= 1MHz | - | 0.25 | 1 | pF | |

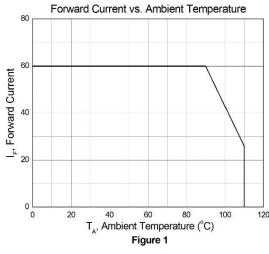
Switching Characteristics

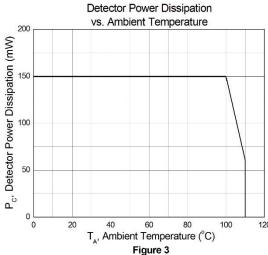
| Symbol | Parameters | Test Conditions | Min | Тур | Max | Units | Notes |
|----------------|------------|--|-----|-----|-----|-------|-------|
| t _r | Rise Time | I _C = 2mA, V _{CE} = 2V | - | 6 | 18 | 0 | |
| t _f | Fall Time | R _L = 100Ω | - | 8 | 18 | μS | |

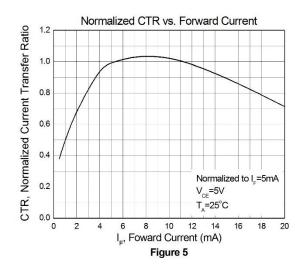


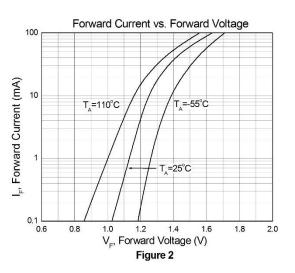


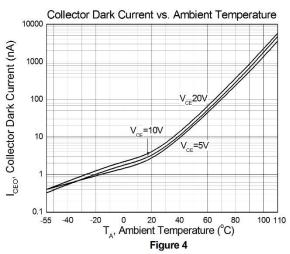
Typical Characteristic Curves

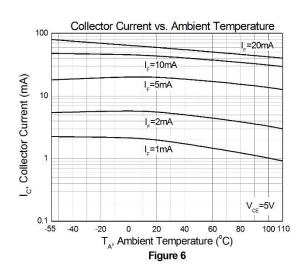






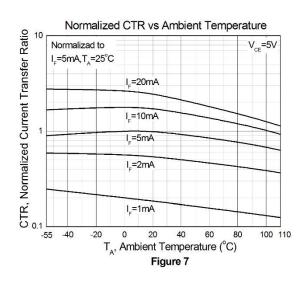


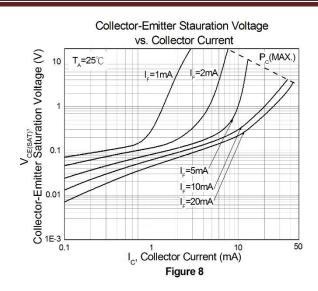


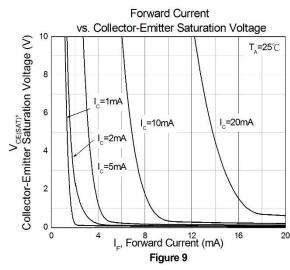


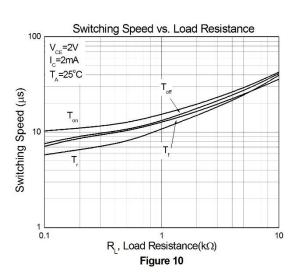


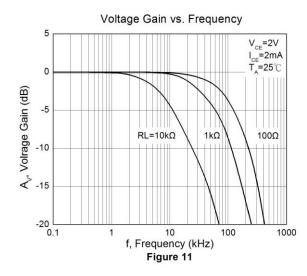
DC Input 4-Pin Phototransistor Optocoupler















Test Circuit

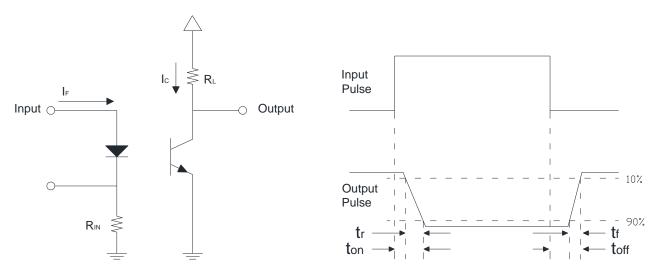


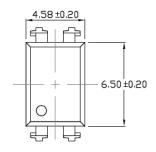
Figure 12: Switching Time Test Circuits

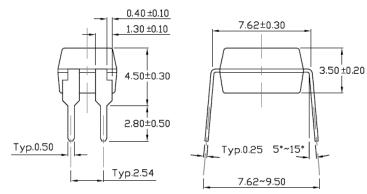




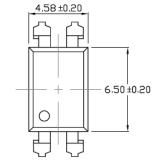
Package Dimension Dimensions in mm unless otherwise stated

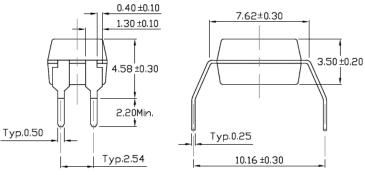
Standard DIP - Through Hole





Gullwing (400mil) Lead Forming – Through Hole (M Type)

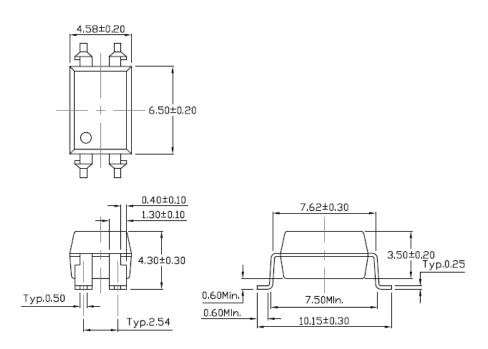




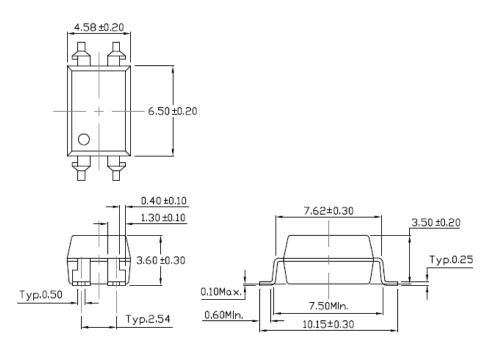




Surface Mount Lead Forming (S Type)



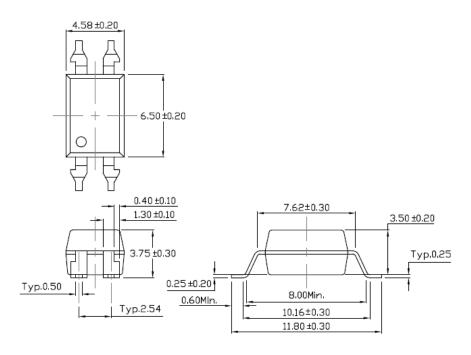
Surface Mount (Low Profile) Lead Forming (SL Type)

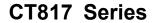




DC Input 4-Pin Phototransistor Optocoupler

Surface Mount (Gullwing) Lead Forming (SLM Type)

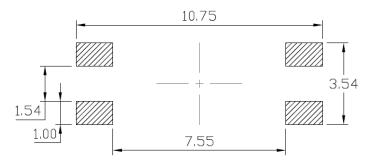




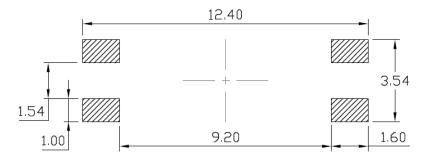


Recommended Solder Mask Dimensions in mm unless otherwise stated

Surface Mount Lead Forming & Surface Mount (Low Profile) Lead Forming



Surface Mount (Gullwing) Lead Forming



Marking Information



Note:

CT : Denotes "CT Micro"

817 : Part NumberV : VDE OptionR : CTR RankY : Fiscal YearWW : Work Week

K : Manufacturing Code





Ordering Information

CT817X(V)(Y)(Z)-HG

X = Part No. (X=A, B, C, D or None)

V = VDE Option (V or None)

Y = Lead form option (S, SL, M, SLM or none)

Z = Tape and reel option (T1, T2, T3, T4 or none)

H = Lead frame option (H: Iron, None: Copper)

G= Material option (G: Green, None: Non-green)

| Option | Description | Quantity |
|---------|---|-----------------|
| None | Standard 4 Pin Dip | 100 Units/Tube |
| М | Gullwing (400mil) Lead Forming | 100 Units/Tube |
| S(T1) | Surface Mount Lead Forming – With Option 1 Taping | 1500 Units/Reel |
| S(T2) | Surface Mount Lead Forming – With Option 2 Taping | 1500 Units/Reel |
| S(T3) | Surface Mount Lead Forming – With Option 3 Taping | 1000 Units/Reel |
| S(T4) | Surface Mount Lead Forming – With Option 4 Taping | 1000 Units/Reel |
| SL(T1) | Surface Mount (Low Profile) Lead Forming– With Option 1 Taping | 1500 Units/Reel |
| SL(T2) | Surface Mount (Low Profile) Lead Forming – With Option 2 Taping | 1500 Units/Reel |
| SL(T3) | Surface Mount (Low Profile) Lead Forming– With Option 3 Taping | 1000 Units/Reel |
| SL(T4) | Surface Mount (Low Profile) Lead Forming – With Option 4 Taping | 1000 Units/Reel |
| SLM(T1) | Surface Mount (Gullwing) Lead Forming– With Option 1 Taping | 1500 Units/Reel |
| SLM(T2) | Surface Mount (Gullwing) Lead Forming – With Option 2 Taping | 1500 Units/Reel |

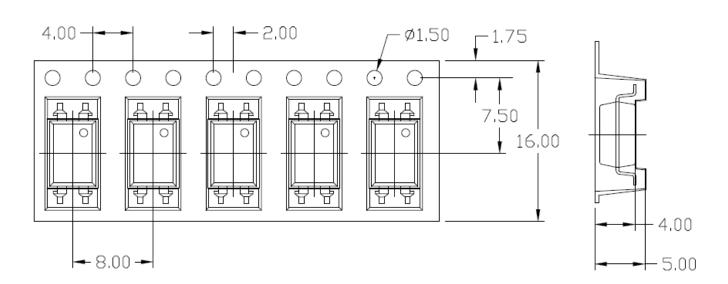


DC Input 4-Pin Phototransistor Optocoupler

Carrier Tape Specifications Dimensions in mm unless otherwise stated

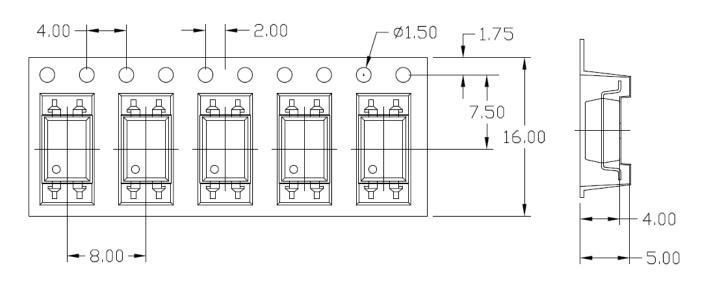
Option S(T1) & SL(T1)

Input Direction



Option S(T2) & SL(T2)

Input Direction

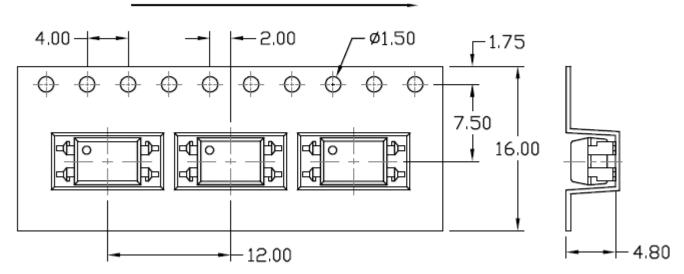




DC Input 4-Pin Phototransistor Optocoupler

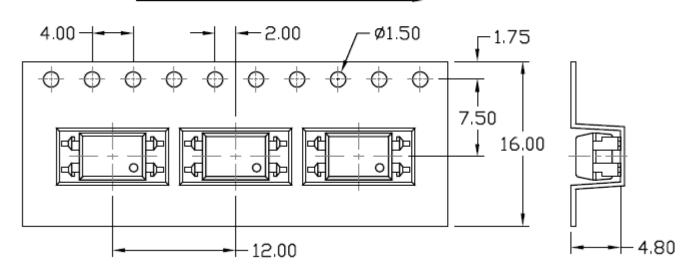
Option S(T3) & SL(T3)

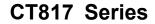
Input Direction



Option S(T4) & SL(T4)

Input Direction

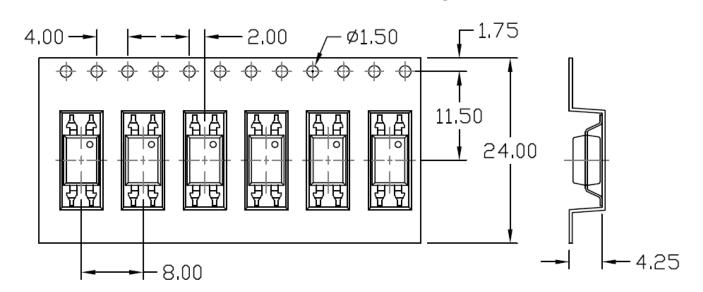






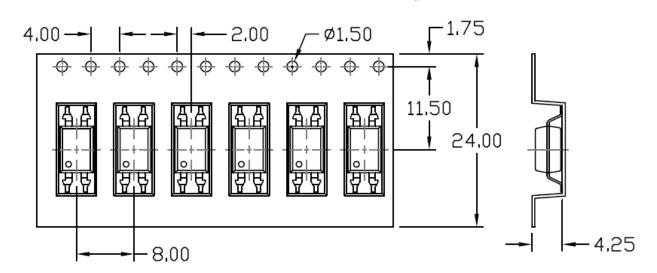
Option SLM(T1)

Input Direction



Option SLM(T2)

Input Direction







Wave soldering (follow the JEDEC standard JESD22-A111)

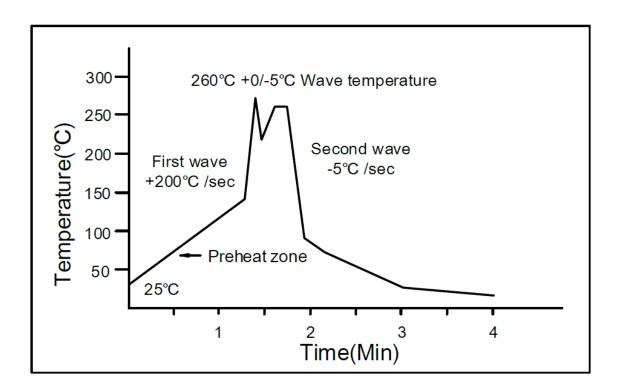
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5°C.

Time: 10 sec.

Preheat temperature:25 to 140°C.

Preheat time: 30 to 80 sec.



Iron soldering (follow the standard MIL-STD 202G, Method 210F)

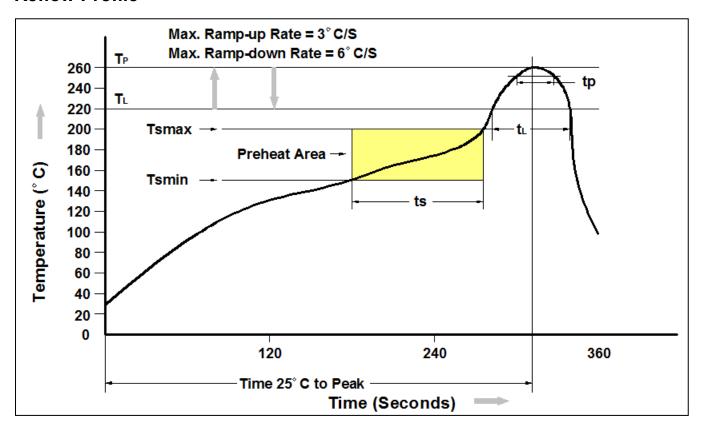
Allow single lead soldering in every single process.

One time soldering is recommended. Temperature: 350+±10°C

Time: 5 sec max.



Reflow Profile



| Profile Feature | Pb-Free Assembly Profile | | | | |
|---|--------------------------|--|--|--|--|
| Temperature Min. (Tsmin) | 150°C | | | | |
| Temperature Max. (Tsmax) | 200°C | | | | |
| Time (ts) from (Tsmin to Tsmax) | 60-120 seconds | | | | |
| Ramp-up Rate (t∟ to t _P) | 3°C/second max. | | | | |
| Liquidous Temperature (T _L) | 217°C | | | | |
| Time (t _L) Maintained Above (T _L) | 60 – 150 seconds | | | | |
| Peak Body Package Temperature | 260°C +0°C / -5°C | | | | |
| Time (t _P) within 5°C of 260°C | 30 seconds | | | | |
| Ramp-down Rate (T_P to T_L) | 6°C/second max | | | | |
| Time 25°C to Peak Temperature | 8 minutes max. | | | | |



DC Input 4-Pin Phototransistor Optocoupler

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